

Prototype Information One Volt SMARTMOS™ Rail-to-Rail Dual Operational Amplifier

The MC33502 operational amplifier provides rail-to-rail operation on both the input and output. The output can swing within 50 mV of each rail. This rail-to-rail operation enables the user to make full use of the entire supply voltage range available. It is designed to work at very low supply voltages (1.0 V and ground), yet can operate with a supply of up to 7.0 V and ground. Output current boosting techniques provide high output current capability while keeping the drain current of the amplifier to a minimum.

- Low Voltage, Single Supply Operation (1.0 V and Ground to 7.0 V and Ground)
- High Input Impedance: Less than 40 fA Input Current
- Typical Unity Gain Bandwidth @ 5.0 V = 5.0 MHz, @ 1.0 V = 4.0 MHz
- High Output Current (I_{SC} = 50 mA @ 5.0 V, 10 mA @ 1.0 V)
- Output Voltage Swings within 50 mV of Both Rails
- Input Voltage Range Includes Both Supply Rails
- High Voltage Gain: 100 dB
- No Phase Reversal on the Output for Over–Driven Input Signals
- Input Offset Trimmed to <500 μV Typical
- Low Supply Current (I_D = 1.2 mA, Typical)
- 600 Ω Drive Capability
- Extended Operating Temperature Range (-40° to +105°C)

APPLICATIONS

- Single Cell NiCd/Ni MH Powered Systems
- Single Cell Lithium Powered Systems
- Portable Communication Devices
- Low Voltage Active Filters
- General Systems Requiring Battery Power



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LOW VOLTAGE RAIL-TO-RAIL DUAL OPERATIONAL AMPLIFIER

SEMICONDUCTOR TECHNICAL DATA





ORDERING INFORMATION

Device	Operating Temperature Range	Package
MC33502P	T. 40% to 1405%C	Plastic DIP
MC33502D	$T_A = -40^{\circ} \text{ to } +105^{\circ}\text{C}$	SO–8

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MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Supply Voltage (V _{CC} to V _{EE})	٧ _S	7.0	V
ESD Protection Voltage at any Pin Human Body Model	VESD	2000	V
Voltage at Any Device Pin	V _{DP}	Vg ±0.3	V
Input Differential Voltage Range	VIDR	V_{CC} to V_{EE}	V
Common Mode Input Voltage Range	VCM	V_{CC} to V_{EE}	V
Output Short Circuit Duration	tS	(Note 1)	S
Maximum Junction Temperature	Тj	+150	°C
Storage Temperature Range	T _{stg}	-65 to +150	°C
Maximum Power Dissipation	PD	(Note 1)	mW

NOTES: 1. Power dissipation must be considered to ensure maximum junction temperature (T_J) is not exceeded.

2. ESD data available upon request.

DC ELECTRICAL CHARACTERISTICS ($V_{CC} = 5.0 \text{ V}$, $V_{EE} = 0 \text{ V}$, $V_{CM} = V_O = V_{CC}/2$, R_L to $V_{CC}/2$, $T_A = 25^{\circ}$ C, unless otherwise noted.)

Characteristic	Figure	Symbol	Min	Тур	Max	Unit
Input Offset Voltage	_	VIO				mV
V _{CC} = 1.0 V		_				
$T_A = +25^{\circ}C$			-	0.5	-	
$T_A = -40^{\circ} \text{ to } +105^{\circ}\text{C}$			-	1.0	-	
$V_{CC} = 3.0 \text{ V}, V_{CM} = 0 \text{ to } V_{CC}$						
$T_A = +25^{\circ}C$			-	0.5	-	
$T_A = -40^{\circ} \text{ to } +105^{\circ}\text{C}$			-	1.0	-	
$V_{CC} = 5.0 \text{ V}, V_{CM} = 0 \text{ to } V_{CC}$						
$T_A = +25^{\circ}C$			-	0.5	-	
$T_A = -40^{\circ} \text{ to } +105^{\circ}\text{C}$			-	1.0	-	
Input Offset Voltage Temperature Coefficient (R _S = 50 Ω)	-	$\Delta V_{IO} / \Delta T$	-	2.0	-	μV/°C
$T_A = -40^\circ$ to $+105^\circ$ C						
Input Bias Current	-	I _{IB}				fA
$V_{CC} = 1.0 V$			_	40	_	
$V_{CC} = 3.0 V$			-	40	-	
$V_{CC} = 5.0 V$			-	40	-	
Common Mode Input Voltage Range	-	VICR	VEE	_	Vcc	V
Large Signal Voltage Gain	_	Avol				kV/V
$V_{CC} = 1.0 V (T_A = +25^{\circ}C)$						
$R_L = 10 \text{ k}\Omega$			-	100	-	
$R_{\rm I} = 1.0 \rm k\Omega$			-	50	-	
V_{CC} = 1.0 V (T _A = -40° to +105°C)						
$R_L = 10 \text{ k}\Omega$			-	-	-	
$R_{L} = 1.0 \text{ k}\Omega$			-	-	-	
$V_{CC} = 3.0 V (T_A = +25^{\circ}C)$						
$R_L = 10 \ k\Omega$			-	500	-	
$R_{L} = 1.0 k\Omega$			-	100	-	
$V_{CC} = 3.0 \text{ V} (T_{A} = -40^{\circ} \text{ to } +105^{\circ}\text{C})$						
$R_L = 10 \text{ k}\Omega$			-	-	-	
$R_L = 1.0 \text{ k}\Omega$			-	-	-	
$V_{CC} = 5.0 V (T_A = +25^{\circ}C)$						
$R_{L} = 10 k\Omega$			-	500	-	
$R_{L} = 1.0 k\Omega$			-	200	-	
$V_{CC} = 5.0 \text{ V} (T_{A} = -40^{\circ} \text{ to } +105^{\circ}\text{C})$						
$R_{L} = 10 \ k\Omega$			-	-	-	
$R_L = 1.0 k\Omega$			-	-	-	

Characteristic	Figure	Symbol	Min	Тур	Max	Unit
Output Voltage Swing, High ($V_{ID} = \pm 0.2 V$)	_	VOH				V
$V_{CC} = 1.0 V (T_{A} = +25^{\circ}C)$		_				
$R_{L} = 10 k\Omega$			-	0.95	-	
$R_{I} = 600 \Omega$			-	0.88	-	
$V_{CC} = 1.0 V (T_{A} = -40^{\circ} \text{ to } +105^{\circ}\text{C})$						
$R_L = 10 k\Omega$			-	_	-	
$R_{L} = 600 \Omega$			_	_	_	
$V_{CC} = 3.0 V (T_A = +25^{\circ}C)$						
$R_L = 10 k\Omega$			_	2.93	_	
$R_L = 600 \Omega$			_	2.84	_	
$V_{CC} = 3.0 \text{ V} (T_{A} = -40^{\circ} \text{ to } +105^{\circ}\text{C})$				2.04		
$R_L = 10 \ k\Omega$				_		
			-	_	-	
$R_{L} = 600 \Omega$			-	_	-	
$V_{CC} = 5.0 V (T_{A} = +25^{\circ}C)$				4.00		
$R_{L} = 10 k\Omega$			-	4.92	-	
$R_L = 600 \Omega$			-	4.81	-	
$V_{CC} = 5.0 \text{ V} (T_{A} = -40^{\circ} \text{ to } +105^{\circ}\text{C})$						
$R_L = 10 k\Omega$			-	-	-	
$R_L = 600 \Omega$			-	-	-	
Output Voltage Swing, Low ($V_{ID} = \pm 0.2 V$)	-	VOL				V
$V_{CC} = 1.0 V (T_A = +25^{\circ}C)$						
$R_L = 10 k\Omega$			_	0.016	_	
$R_{I} = 600 \Omega$			_	0.047	_	
$V_{CC} = 1.0 V (T_A = -40^{\circ} \text{ to } +105^{\circ}\text{C})$				0.0.1		
$R_L = 10 k\Omega$			_	_	_	
$R_L = 600 \Omega$			_	_	_	
$V_{CC} = 3.0 V (T_{A} = +25^{\circ}C)$				0.00		
$R_L = 10 k\Omega$			-	0.02	-	
$R_{L} = 600 \Omega$			-	0.08	-	
$V_{CC} = 3.0 V (T_{A} = -40^{\circ} \text{ to } +105^{\circ}\text{C})$						
$R_{L} = 10 k\Omega$			-	-	-	
$R_L = 600 \Omega$			-	-	-	
$V_{CC} = 5.0 V (T_{A} = +25^{\circ}C)$						
$R_L = 10 \ k\Omega$			-	0.024	-	
$R_L = 600 \Omega$			-	0.10	-	
$V_{CC} = 5.0 \text{ V} (T_A = -40^{\circ} \text{ to } +105^{\circ}\text{C})$						
$R_{L} = 10 k\Omega$			-	-	-	
$R_{L} = 600 \Omega$			-	-	-	
Common Mode Rejection (V _{in} = 0 to 5.0 V)	_	CMR	_	74	_	dB
Power Supply Rejection Ratio		PSRR				μV/V
	_			50		μν/ν
$V_{CC}/V_{EE} = 5.0 V/Ground to 3.0 V/Ground$			-		-	
$V_{CC}/V_{EE} = 3.0 V/Ground$ to 1.0 V/Ground			-	50	-	
Output Short Circuit Current (V_{in} Diff = ±1.0 V)	-	ISC				mA
$V_{CC} = 1.0 V$						
Source			-	13	-	
Sink			-	13	-	
V _{CC} = 3.0 V						
Source		1	-	32	-	
Sink			-	64	_	
$V_{CC} = 5.0 V$						
Source			_	40	_	
Sink			_	70	_	
		1-				
Power Supply Current (Per Amplifier, $V_0 = 0 V$)	-	ID				mA
$V_{CC} = 1.0 V$			-	1.2	-	
	1	1	I —	1.5	I —	1
V _{CC} = 3.0 V V _{CC} = 5.0 V				1.65	_	

DC ELECTRICAL CHARACTERISTICS (continued) ($V_{CC} = 5.0 \text{ V}$, $V_{EE} = 0 \text{ V}$, $V_{CM} = V_O = V_{CC}/2$, R_L to $V_{CC}/2$, $T_A = 25^{\circ}$ C, unless otherwise noted.)

Characteristic	Figure	Symbol	Min	Тур	Max	Unit
Slew Rate (V _S = ± 2.5 V, V _O = -2.0 V to 2.0 V, R _L = 600 Ω , A _V = 1.0)	-	SR				V/µs
Positive Slope			-	4.0	-	
Negative Slope			-	-3.0	-	
Unity Gain Bandwidth	-	BW				MHz
V _{CC} = 1.0 V			-	4.0	-	
$V_{CC} = 3.0 V$			-	5.0	-	
$V_{CC} = 5.0 V$			-	5.0	-	
Gain Margin (R _L =10 k Ω , C _L = 0 pF)	-	Am	-	6.5	_	dB
Phase Margin (R _L = 10 k Ω , C _L = 0 pF)	-	Øm	-	60	-	Deg
Channel Separation (f = 1.0 Hz to 20 kHz, R_L = 600 Ω)	-	CS	-	120	-	dB
Power Bandwidth (V_O = 4.0 Vpp, R_L = 1.0 k\Omega, THD \leq 1.0%)	-	BWP	-	200	-	kHz
Total Harmonic Distortion (V _O = 4.5 Vpp, R _L = 600 Ω , A _V = 1.0)	-	THD				%
f = 1.0 kHz			-	0.004	-	
f = 10 kHz			-	0.01	-	
Differential Input Resistance ($V_{CM} = 0 V$)	-	R _{in}	-	>1.0	-	terraΩ
Differential Input Capacitance ($V_{CM} = 0 V$)	-	C _{in}	-	2.0	-	pF
Equivalent Input Noise Voltage (V_{CC} = 1.0 V, V_{CM} = 0 V, V_{EE} = Gnd,	-	e _n				nV/√Hz
$R_S = 100 \Omega$)						
f = 10 kHz			-	60	-	
f = 1.0 kHz			_	30	_	

Figure 1. Representative Block Diagram



GENERAL INFORMATION

The MC33502 dual operational amplifier is unique in its ability to provide 1.0 V rail–to–rail performance on both the input and output by using a SMARTMOS process. The amplifier output swings within 50 mV of both rails and is able to provide 50 mA of output drive current with a 5.0 V supply, and 10 mA with a 1.0 V supply. A 5.0 MHz bandwidth and a slew rate of 3.0 V/µs is achieved with high speed depletion mode NMOS (DNMOS) and vertical PNP transistors. This device is characterized over a temperature range of -40° C to 105° C.

CIRCUIT INFORMATION Input Stage

One volt rail-to-rail performance is achieved in the MC33502 at the input by using a single pair of depletion mode NMOS devices (DNMOS) to form a differential amplifier with a very low input current of 40 fA. The normal input common mode range of a DNMOS device, with an ion implanted negative threshold, includes ground and relies on the body effect to dynamically shift the threshold to a positive value as the gates are moved from ground towards the positive supply. Because the device is manufactured in a p-well process, the body effect coefficient is sufficiently large to ensure that the input stage will remain saturated when the inputs are at the positive rail. This also applies at very low supply voltages. The 1.0 V rail-to-rail input stage consists of a DNMOS differential amplifier, a folded cascode, and a low voltage balanced mirror. The low voltage cascoded balanced mirror provides high 1st stage gain and base current cancellation without sacrificing signal integrity. Also, the input offset voltage is trimmed to less than 1.0 mV because of the limited available supply voltage. The body voltage of the input DNMOS differential pair is internally trimmed to minimize the input offset voltage. A common mode feedback path is also employed to enable the offset voltage to track over the input common mode voltage. The total operational amplifier quiescent current drop is 1.3 mA/amp.

Output Stage

An additional feature of this device is an "on demand" base current cancellation amplifier. This feature provides base drive to the output power devices by making use of a buffer amplifier to perform a voltage-to-current conversion. This is done in direct proportion to the load conditions. A buffer is necessary to isolate the load current effects in the output stage from the input stage. Because of the low voltage conditions, a DNMOS follower is used to provide an essentially zero voltage level shift. This buffer isolates any load current changes on the output stage from loading the input stage. This "on demand" feature allows these amplifiers to consume only a few micro-amps of current when the output stage is in its quiescent mode. Yet it provides high output current when required by the load. The rail-to-rail output stage current boost circuit provides 50 mA of output current with a 5.0 V supply (For a 1.0 V supply output stage will do 10 mA) enabling the operational amplifier to drive a 600 Ω load. A high speed vertical PNP transistor provides excellent frequency performance while sourcing current. The operational amplifier is also internally compensated to provide a phase margin of 60 degrees. It has a unity gain of 5.0 MHz with a 5.0 V supply and 4.0 MHz with a 1.0 V supply.

LOW VOLTAGE OPERATION

The MC33502 will operate at supply voltages from 0.9 V to 7.0 V and ground. Since the device is rail-to-rail on both input and output, high dynamic range single battery cell applications are now possible.





Figure 5. Gain and Phase versus Frequency



Figure 6. Transient Response f(t) = 0 f

Figure 7. Slew Rate



OUTLINE DIMENSIONS



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